

## -30V Dual P-Channel Fast Switching MOSFETs

### DESCRIPTION

The SMC4931 is the Dual P-Channel logic enhancement mode power field effect transistor is produced using high cell density, advanced trench technology to provide excellent  $R_{DS(ON)}$ . This device is suitable for use as a load switch or in PWM and gate charge for most of the synchronous buck converter applications.

*SMC4931M-TRG ROHS Compliant This is Halogen Free*

### FEATURE

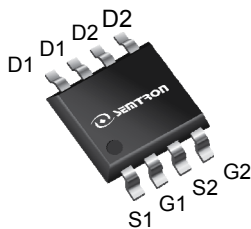
- ◆ **-30V/-7.0A,  $R_{DS(ON)} = 21m\Omega(typ.)@V_{GS} = -10V$**
- ◆ **-30V/-5.5A,  $R_{DS(ON)} = 27m\Omega(typ.)@V_{GS} = -4.5V$**
- ◆ Super high density cell design for extremely low  $R_{DS(ON)}$
- ◆ Exceptional on-resistance and Maximum DC current capability

### APPLICATIONS

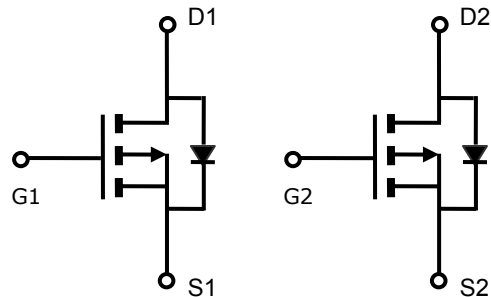
- ◆ Power Management in Note book
- ◆ Portable Equipment
- ◆ DSC
- ◆ LCD Display inverter
- ◆ Battery Powered System
- ◆ DC/DC Converter
- ◆ Load Switch



### PIN CONFIGURATION



SOP-8  
Top View



### PART NUMBER INFORMATION

|  |   |
|--|---|
| <p><b>SMC 4931 M - TR G</b></p> <p>a    b    c    d    e</p> | <p>a : Company name.<br/> b : Product Serial number.<br/> c : Package code<br/> d : Handling code<br/> e : Green produce code</p> |
|--|---|

## ORDERING INFORMATION

| Part Number  | Package Code | Handling Code  | Shipping  |
|--------------|--------------|----------------|-----------|
| SMC4931M-TRG | M : SOP-8    | TR : Tape&Reel | 2.5K/Reel |

- ※ Year Code : 0 ~ 9, 2010 : 0
- ※ Week Code : 01 ~ 02 : A, 03 ~ 04 = B...
- ※ SOP-8 : Only available in tape and reel packaging.

## ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ Unless otherwise noted )

| Symbol    | Parameter  | Typical                | Unit             |
|-----------|--|------------------------|------------------|
| $V_{DSS}$ | Drain-Source Voltage                             | -30                    | V                |
| $V_{GSS}$ | Gate-Source Voltage                              | $\pm 20$               | V                |
| $I_D$     | Continuous Drain Current, $V_{GS}=10V^A$         | $T_A=25^\circ\text{C}$ | -7.0             |
|           |  | $T_A=70^\circ\text{C}$ | -5.8             |
| $I_{DM}$  | Pulsed Drain Current <sup>B</sup>                | -27                    | A                |
| $E_{AS}$  | Single Pulse Avalanche energy $L=0.1\text{mH}^C$ | 160                    | mJ               |
| $P_D$     | Power Dissipation                                | $T_A=25^\circ\text{C}$ | 2.0              |
|           |  | $T_A=70^\circ\text{C}$ | 1.4              |
| $T_J$     | Operation Junction Temperature                   | -55/150                | $^\circ\text{C}$ |
| $T_{STG}$ | Storage Temperature Range                        | -55/150                | $^\circ\text{C}$ |

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.  
 Absolute maximum ratings are stress ratings only and functional device operation is not implied.

## THERMAL DATA

| Symbol          | Parameter   | Min | Typ | Max | Unit                      |
|-----------------|---|-----|-----|-----|---------------------------|
| $R_{\theta JA}$ | Thermal Resistance-Junction to Ambient <sup>A</sup> |     |     | 85  | $^\circ\text{C}/\text{W}$ |
| $R_{\theta JC}$ | Thermal Resistance Junction to Lead <sup>A</sup>    |     |     | 60  | $^\circ\text{C}/\text{W}$ |

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ Unless otherwise noted )

| Symbol                    | Parameter                               | Condition   | Min  | Typ      | Max       | Unit       |
|---------------------------|---|---|------|----------|-----------|------------|
| <b>Static Parameters</b>  |   |   |      |          |           |            |
| $V_{(BR)DSS}$             | Drain-Source Breakdown Voltage          | $V_{GS} = 0V, I_D = -250\mu A$                                | -30  |          |           | V          |
| $V_{GS(th)}$              | Gate Threshold Voltage                  | $V_{DS} = V_{GS}, I_D = -250\mu A$                            | -1.0 |          | -2.0      | V          |
| $I_{GSS}$                 | Gate Leakage Current                    | $V_{DS} = 0V, V_{GS} = \pm 20V$                               |      |          | $\pm 100$ | nA         |
| $I_{DSS}$                 | Zero Gate Voltage Drain Current         | $V_{DS} = -24V, V_{GS} = 0V$<br>$T_J = 25^\circ\text{C}$      |      |          | -1        | $\mu A$    |
|                           |   | $V_{DS} = -24V, V_{GS} = 0V$<br>$T_J = 55^\circ\text{C}$      |      |          | -5        |            |
| $R_{DS(ON)}$              | Drain-source On-Resistance <sup>B</sup> | $V_{GS} = -10V, I_D = -7.0A$<br>$V_{GS} = -4.5V, I_D = -5.5A$ |      | 21<br>27 | 26<br>32  | m $\Omega$ |
| $G_{fs}$                  | Forward Transconductance                | $V_{DS} = -10V, I_D = -6.0A$                                  |      | 5.5      |           | S          |
| <b>Source-Drain Diode</b> |   |   |      |          |           |            |
| $V_{SD}$                  | Diode Forward Voltage <sup>B</sup>      | $I_S = -1.0A, V_{GS} = 0V$                                    |      | -0.8     | -1.2      | V          |
| $I_S$                     | Continuous Source Current <sup>AD</sup> |   |      |          | -6        | A          |
| <b>Dynamic Parameters</b> |   |   |      |          |           |            |
| $Q_g (-4.5V)$             | Total Gate Charge                       | $V_{DS} = -15V, V_{GS} = -4.5V$<br>$I_D = -5.3A$              |      | 12.5     |           | nC         |
| $Q_{gs}$                  | Gate-Source Charge                      |   |      | 4.7      |           |            |
| $Q_{gd}$                  | Gate-Drain Charge                       |   |      | 4.7      |           |            |
| $C_{iss}$                 | Input Capacitance                       | $V_{DS} = -15V, V_{GS} = 0V$<br>$f = 1\text{MHz}$             |      | 1365     |           | pF         |
| $C_{oss}$                 | Output Capacitance                      |   |      | 198      |           |            |
| $C_{rss}$                 | Reverse Transfer Capacitance            |   |      | 160      |           |            |
| $t_{d(on)}$               | Turn-On Time                            | $V_{DD} = -15V, V_{GEN} = -10V,$<br>$R_G = 3.3\Omega,$        |      | 4.7      |           | nS         |
| $t_r$                     |   |   |      | 14.8     |           |            |
| $t_{d(off)}$              | Turn-Off Time                           |   |      | 40       |           |            |
| $t_f$                     |   |   |      | 19.7     |           |            |

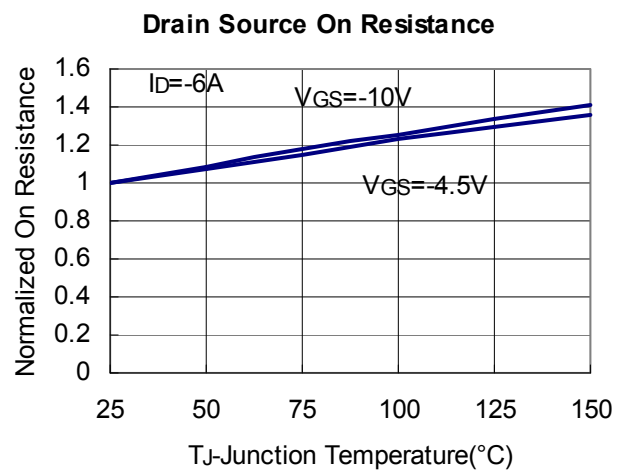
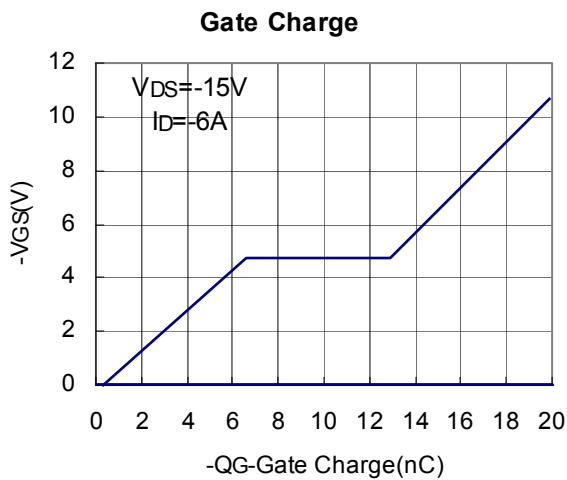
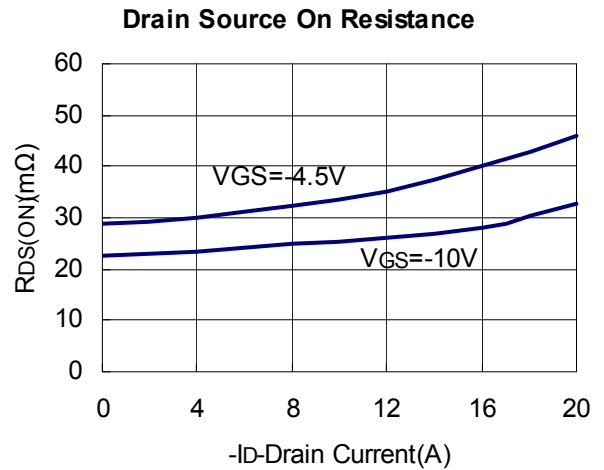
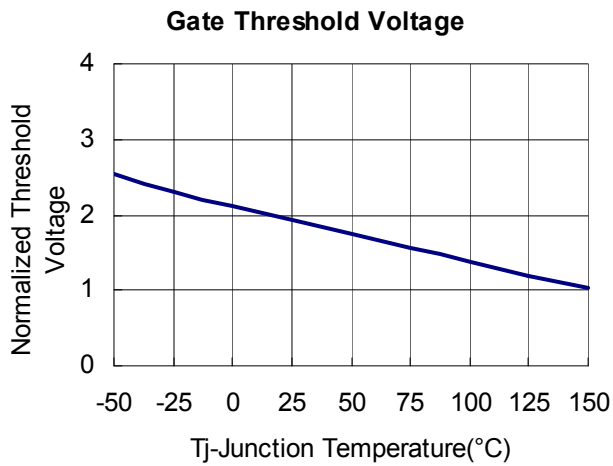
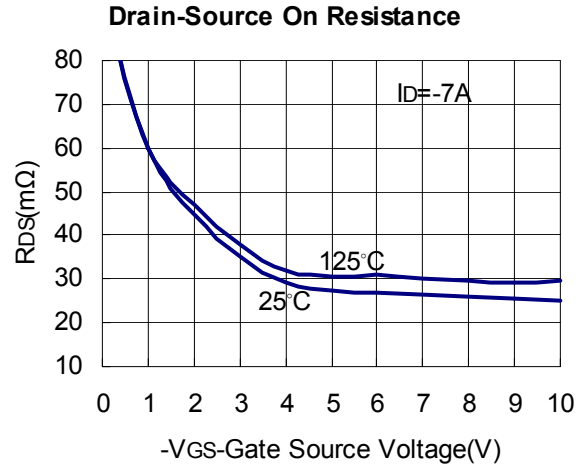
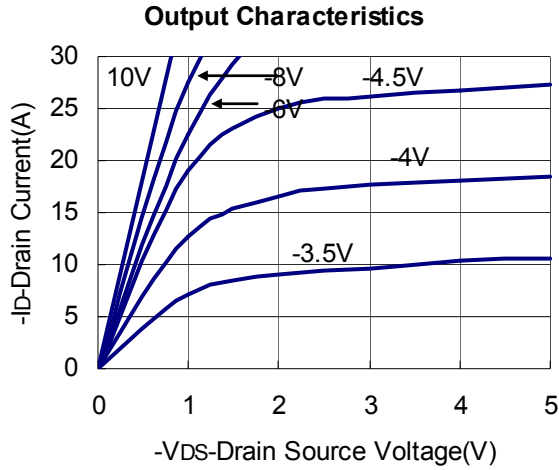
Note:

- The value of  $R_{\theta JA}$  is measured with the device mounted on 1in 2 FR-4 board with 2oz. Copper, in a still air environment with  $T_A = 25^\circ\text{C}$ .
- The data tested by pulsed, pulse width  $\leq 300\mu\text{s}$ , duty cycle  $\leq 2\%$
- The EAS data shows Max. rating. The test condition is  $V_{DD} = -25V, V_{GS} = -10V, L = 0.1\text{mH}$ .
- The data is theoretically the same as  $I_D$  and  $I_{DM}$ , in real applications, should be limited by total power dissipation.

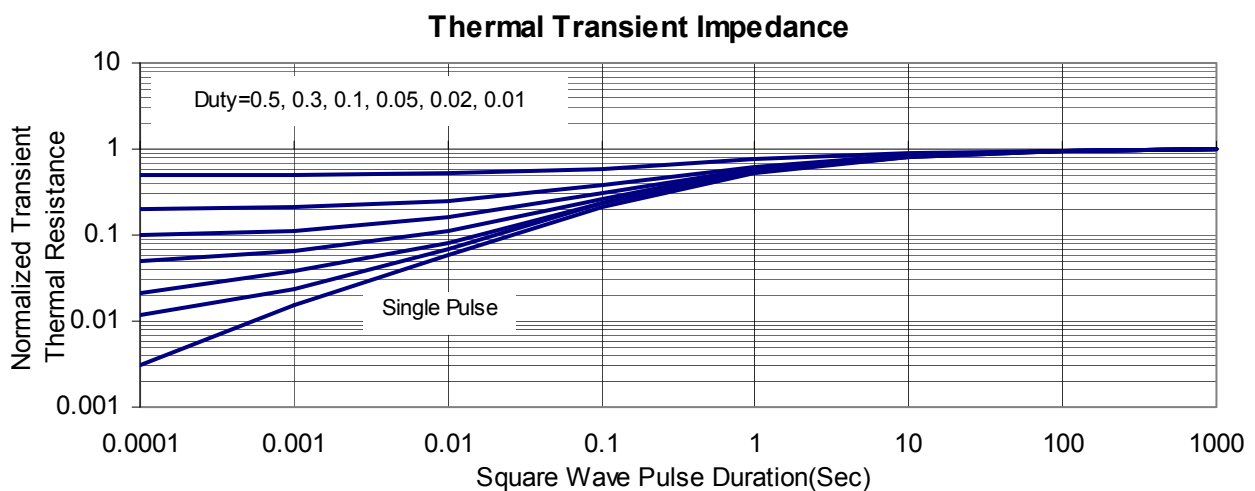
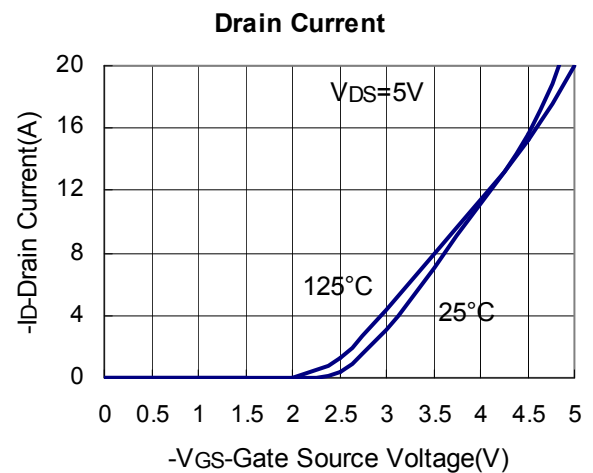
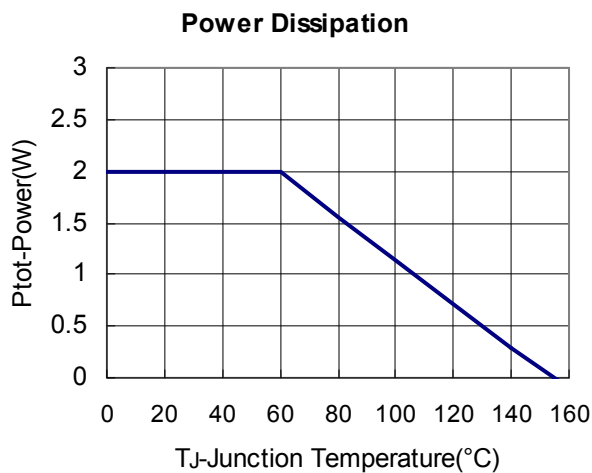
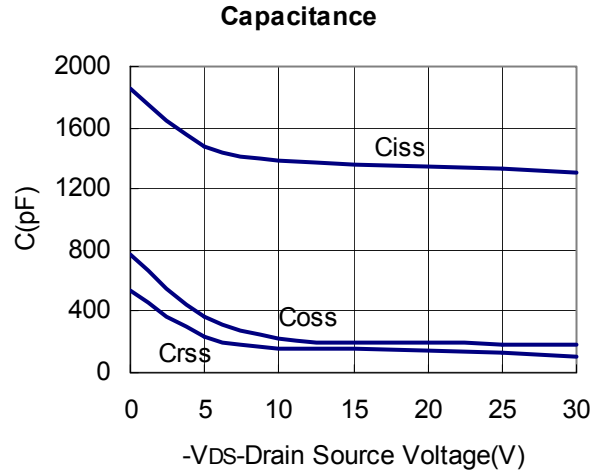
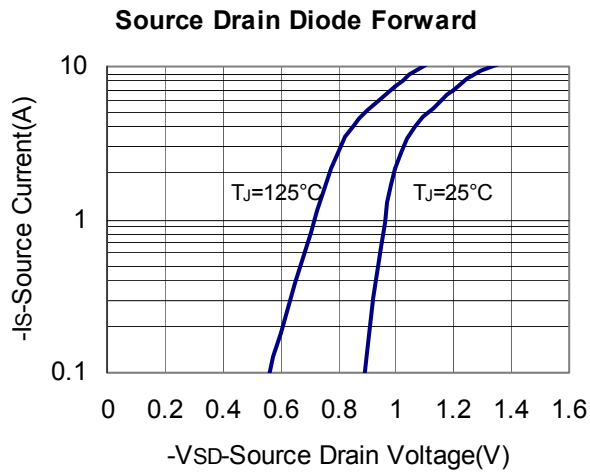
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## TYPICAL CHARACTERISTICS



## TYPICAL CHARACTERISTICS



## ■ SOP-8 PACKAGE DIMENSIONS

| Symbol   | Dimensions In Millimeters |       | Dimensions In Inches |       |
|----------|---------------------------|-------|----------------------|-------|
|          | Min.                      | Max.  | Min.                 | Max.  |
| A        | 1.350                     | 1.750 | 0.053                | 0.069 |
| A1       | 0.100                     | 0.250 | 0.040                | 0.010 |
| A2       | 1.350                     | 1.550 | 0.053                | 0.061 |
| b        | 0.330                     | 0.510 | 0.013                | 0.020 |
| c        | 0.170                     | 0.250 | 0.006                | 0.010 |
| D        | 4.700                     | 5.100 | 0.185                | 0.200 |
| E        | 3.800                     | 4.000 | 0.150                | 0.157 |
| E1       | 5.800                     | 6.200 | 0.228                | 0.244 |
| e        | 1.270 BSC                 |       | 0.050 BSC            |       |
| L        | 0.400                     | 1.270 | 0.016                | 0.050 |
| $\theta$ | 0°                        | 8°    | 0°                   | 8°    |

